

3.2 W Mono Class-D Audio Power Amplifier With Selectable Gain and Auto-Recovering Short-Circuit Protection

Check for Samples: TPA2038D1

FEATURES

- Filter-Free Mono Class-D Speaker Amp
- GAIN Pin Selects Between 6 dB and 12 dB
- + 3.2 W into 4 Ω from 5 V supply at 10% THD+N
- Powerful Mono Class-D Speaker Amplifier
 - 1% at 1.4 W into 8 Ω from 5 V Supply
 - 1% at 2.5 W into 4 Ω from 5 V Supply
- Integrated Image Reject Filter for DAC Noise Reduction
- Low Output Noise of 20 μ V
- Low Quiescent Current of 1.5 mA
- Auto-Recovering Short-Circuit Protection
- Thermal-Overload Protection
- 9-Ball 1,21 mm × 1,16 mm 0,4 mm Pitch WCSP

APPLICATIONS

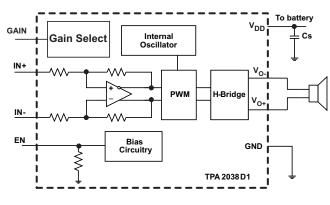
- Wireless or Cellular Handsets and PDAs
- Portable Navigation Devices
- General Portable Audio Devices

DESCRIPTION

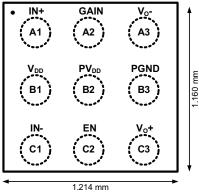
The TPA2038D1 is a 3.2 W into 8-ohm (10% THD) high efficiency filter-free class-D audio power amplifier. The GAIN pin sets gain to either 6 dB or 12 dB.

Features like 95% efficiency, 1.5 mA quiescent current, 0.5 μ A shutdown current, 81 dB PSRR, 20 μ V output noise, and improved RF immunity make the TPA2038D1 class-D amplifier ideal for cellular handsets. A start-up time is within 4 ms with no turn-on pop.

The TPA2038D1 is available in a 1.21 mm x 1.16 mm, 0.4 mm pitch wafer chip scale package (WCSP).



TPA 2038D1 9-BALL 0.4mm PITCH WAFER CHIP SCALE PACKAGE (YFF) (TOP VIEW OF PCB)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

APPLICATION CIRCUIT

TPA2038D1

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

T _A	PACKAGED DEVICES ⁽¹⁾ PART NUMBER ⁽²⁾		SYMBOL
-40°C to 85°C		TPA2038D1YFFR	QWK
	9-ball WCSP	TPA2038D1YFFT	QWK

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com

(2) The YFF package is only available taped and reeled. The suffix "R" indicates a reel of 3000, the suffix "T" indicates a reel of 250.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range, $T_A = 25^{\circ}C$ (unless otherwise noted)⁽¹⁾

			VALUE	UNIT
V_{DD} , PV_{DD}	Supply voltage	In active mode	-0.3 to 6.0	V
	Supply voltage	In shutdown mode	-0.3 to 6.0	V
VI	Input voltage	EN, IN+, IN–	–0.3 to V _{DD} + 0.3	V
R _L	Minimum load re	sistance	3.2	Ω
	Output continuou	is total power dissipation	See Dissipation Rating Table	
T _A	Operating free-ai	r temperature range	-40 to 85	°C
TJ	Operating junction	n temperature range	-40 to 150	°C
T _{stg}	Storage tempera	ture range	-65 to 85	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

PACKAGE	DERATING FACTOR ⁽¹⁾	T _A < 25°C	T _A = 70°C	T _A = 85°C	
YFF (WCSP)	4.2 mW/°C	525 mW	336 mW	273 mW	

(1) Derating factor measure with high K board.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V _{DD} , PV _{DD}	Class-D supply voltage		2.5	5.5	V
VIH	High-level input voltage	EN, GAIN	1.3		V
VIL	Low-level input voltage	EN, GAIN		0.35	V
V _{IC}	Common mode input voltage range	V _{DD} = 2.5 V, 5.5 V, CMRR ≥ 49 dB	0.75	V _{DD} -1.1	V
T _A	Operating free-air temperature		-40	85	°C

GAIN SETTING

GAIN PIN	GAIN SETTING		
GND	12 dB		
VDD	6 dB		



ELECTRICAL CHARACTERISTICS

 $PVDD = VDD = 3.6 V, T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OS}	Output offset voltage (measured differentially)	VDD = 2.5 V to 5.5 V, GAIN = VDD		1	5	mV
I _{IH}	High-level EN input current	VDD = 5.5 V, EN = GAIN = 5.5 V			50	μA
I _{IL}	Low-level EN input current	VDD = 5.5 V, EN = GAIN = 0 V			1	μA
		VDD = 5.5 V, no load		1.8	2.5	
I _(Q)	Quiescent current	VDD = 3.6 V, no load		1.5	2.3	mA
		VDD = 2.5 V, no load		1.3	2.1	
I _(SD)	Shutdown current	EN = 0.35 V, VDD = 3.6 V		0.1	2	μA
R _{O, SD}	Output impedance in shutdown mode	EN = 0.35 V		2		kΩ
f _(SW)	Switching frequency	VDD = 2.5 V to 5.5 V	250	300	350	kHz
A _V	Gain	GAIN = 0 V	11.5	12	12.5	.ID
		GAIN = VDD	5.5	6	6.5	dB
R _{EN}	Resistance from EN to GND			300		kΩ
		$A_V = 6 \text{ dB}; \text{EN} = \text{VDD}$		150		
R _{IN}	Single-ended input resistance	$A_V = 12 \text{ dB}; \text{ EN} = \text{VDD}$		75		kΩ
		EN = 0.35 V		75		

OPERATING CHARACTERISTICS

 $\mathsf{PVDD}=\mathsf{VDD}=3.6$ V, $\mathsf{A}_\mathsf{V}=6$ dB, $\mathsf{T}_\mathsf{A}=25^\circ\mathsf{C},$ $\mathsf{R}_\mathsf{L}=8$ Ω (unless otherwise noted)

	PARAMETER	TEST CONDITIO	NS	MIN TYP	MAX	UNIT	
			$V_{DD} = 5 V$	3.24			
		THD + N = 10%, f = 1 kHz, R ₁ = 4 Ω	V _{DD} = 3.6 V	1.62		W	
		112	V _{DD} = 2.5 V	0.70			
			$V_{DD} = 5 V$	2.57			
		THD + N = 1%, f = 1 kHz, R ₁ = 4 Ω	$V_{DD} = 3.6 V$	1.32		W	
D			$V_{DD} = 2.5 V$	0.57			
Po	Output power		$V_{DD} = 5 V$	1.80			
		THD + N = 10%, f = 1 kHz, R ₁ = 8 Ω	$V_{DD} = 3.6 V$	0.91		W	
			$V_{DD} = 2.5 V$	0.42		1	
		THD + N = 1%, f = 1 kHz, R ₁ = 8 Ω	$V_{DD} = 5 V$	1.46		W	
			$V_{DD} = 3.6 V$	0.74			
			$V_{DD} = 2.5 V$	0.33			
	Output voltage noise, $A_V = 6 \text{ dB}$	$V_{DD} = 3.6 V$, Inputs AC	A-weighting	20			
E		grounded with $C_1 = 2 \mu F$, f = 20 Hz to 20 kHz	No weighting	26			
E _N			A-weighting	27		μV _{RMS}	
	Output voltage noise, $A_V = 12 \text{ dB}$		No weighting	36			
		$VDD = 5.0 V, P_0 = 1.0 W, f = 100 V$	1 kHz, $R_L = 8 \Omega$	0.12%			
		$VDD = 3.6 V, P_0 = 0.5 W, f = 100$	1 kHz, $R_L = 8 \Omega$	0.05%			
THD+N	Total harmonia distartion plus poiss	$VDD = 2.5 V, P_0 = 0.2 W, f = 100$	1 kHz, $R_L = 8 \Omega$	0.05%			
	Total harmonic distortion plus noise	$VDD = 5.0 V, P_0 = 2.0 W, f = 7$	1 kHz, $R_L = 4 \Omega$	0.32%			
		VDD = 3.6 V, P _O = 1.0 W, f = 7	1 kHz, $R_L = 4 \Omega$	0.11%			
		$VDD = 2.5 V, P_0 = 0.4 W, f = 7$	0.12%				
		$A_V = 6 \text{ dB}$, Inputs AC grounder 200 mV _{pp} ripple, f = 217 Hz	d with $C_I = 2 \ \mu F$,	81		٩D	
PSRR	AC power supply rejection ratio	$A_V = 12 \text{ dB}$, Inputs AC ground $C_I = 2 \mu F$, 200 mV _{pp} ripple, f =	82		dB		

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OPERATING CHARACTERISTICS (continued)

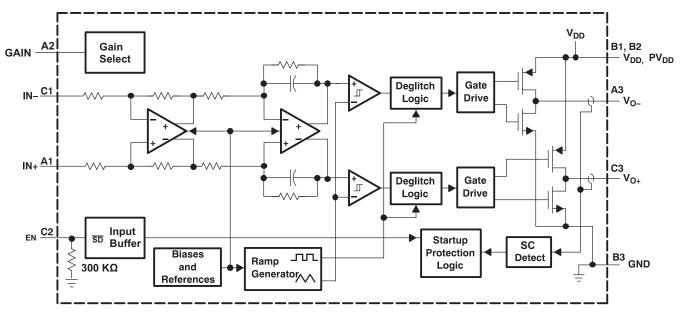
PVDD = VDD = 3.6 V, $A_V = 6 \text{ dB}$, $T_A = 25^{\circ}\text{C}$, $R_L = 8 \Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CMRR Common mode rejection ratio		$A_V = 6 \text{ dB}, V_{IC} = 200 \text{ mV}_{PP}, \text{ f} = 217 \text{ Hz}$		79		dB
		$A_V = 12 \text{ dB}, V_{IC} = 200 \text{ mV}_{PP}, \text{ f} = 217 \text{ Hz}$		77		uБ
Τ _{SU}	Startup time from shutdown			4		ms
		V _{O+} shorted to VDD				
		V _{O-} shorted to VDD				
I _{SC}	Short circuit protection threshold	V _{O+} shorted to GND		2		А
		V _{O-} shorted to GND				
		V_{O+} shorted to V_{O-}				
T _{AR}	Overcurrent recovery time	VDD = 2.5 V to 5.5 V		100		ms

Terminal Functions

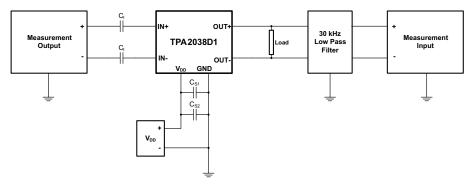
TERMINAL		I/O	DESCRIPTION			
NAME	WCSP BALL	1/0	DESCRIPTION			
IN+	A1	Ι	Positive audio input.			
GAIN	A2	Ι	Gain select. Set to GND for 12 dB; set to VDD for 6 dB.			
V _{O-}	A3	0	Negative audio output.			
VDD	B1	Ι	Power supply terminal. Connect to PVDD using a direct connection.			
PVDD	B2	Ι	Class-D output power supply. Connect to VDD using a direct connection.			
GND	B3	Ι	Ground.			
IN–	C1	I	Negative audio input.			
EN	C2	Ι	Enable. Set to logic high to enable device.			
V _{O+}	C3	0	Positive audio output.			

FUNCTIONAL BLOCK DIAGRAM





TEST SETUP FOR GRAPHS



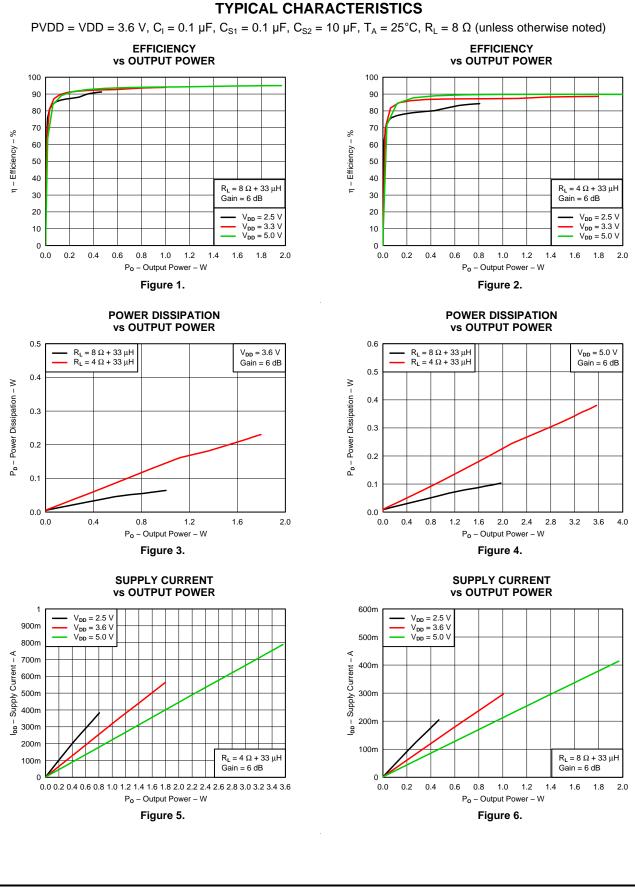
- 1. C_1 was shorted for any common-mode input voltage measurement. All other measurements were taken with $C_1 = 0.1 \ \mu F$ (unless otherwise noted).
- 2. $C_{S1} = 0.1 \ \mu\text{F}$ is placed very close to the device. The optional $C_{S2} = 10 \ \mu\text{F}$ is used for datasheet graphs.
- 3. The 30 kHz low-pass filter is required even if the analyzer has an internal low-pass filter. An RC low-pass filter (1 k Ω , 4700 pF) is used on each output for the data sheet graphs.

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NSTRUMENTS

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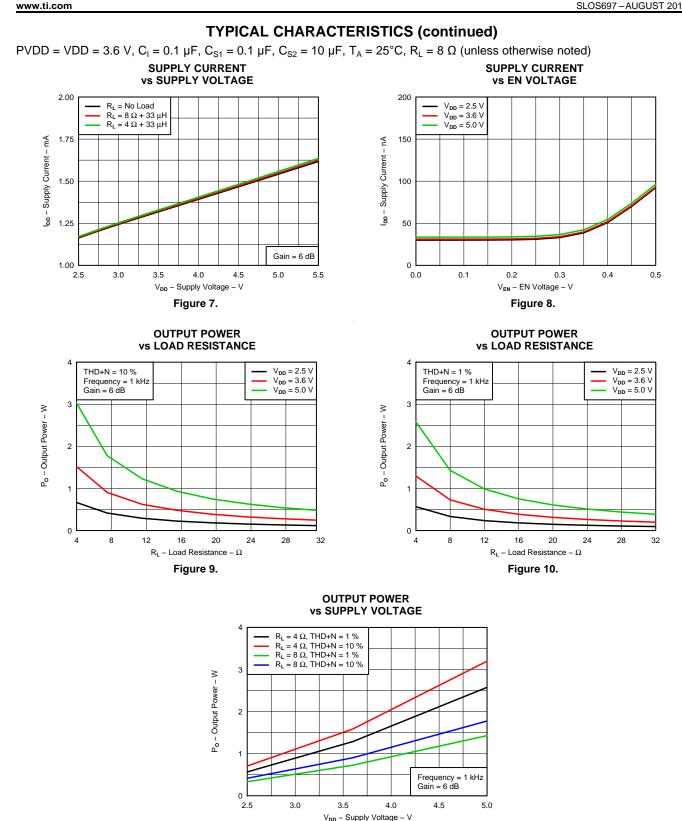
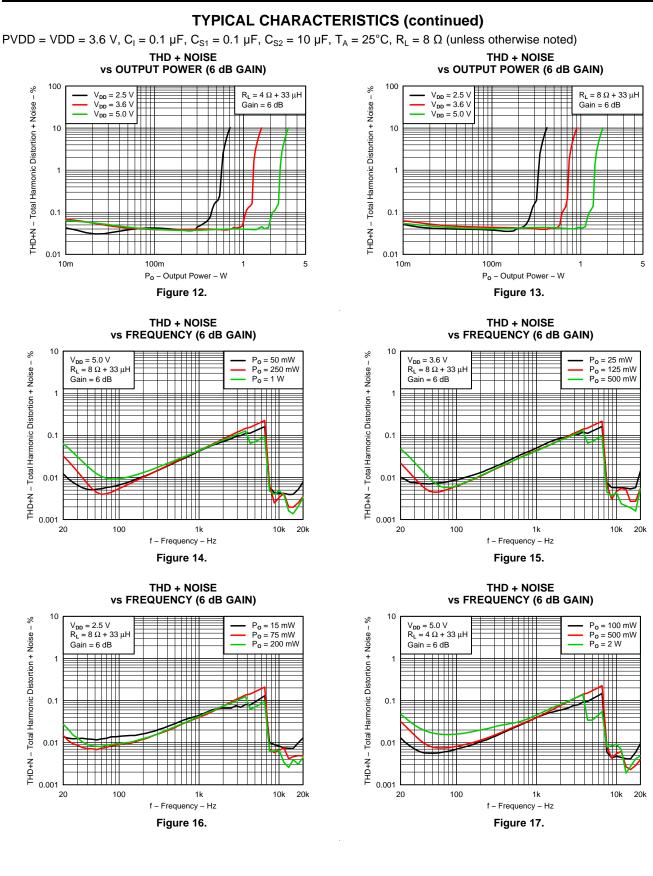


Figure 11.

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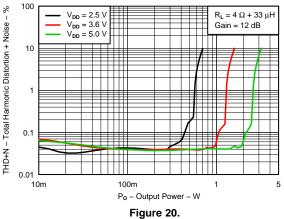


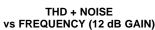
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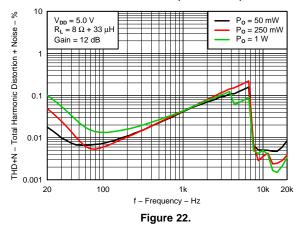
> 10k 20k

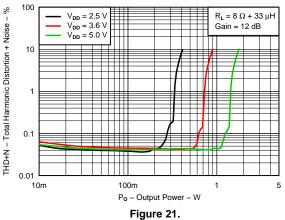


TYPICAL CHARACTERISTICS (continued) $\mathsf{PVDD} = \mathsf{VDD} = 3.6 \text{ V}, \text{ } \text{C}_{\text{I}} = 0.1 \text{ } \mu\text{F}, \text{ } \text{C}_{\text{S1}} = 0.1 \text{ } \mu\text{F}, \text{ } \text{C}_{\text{S2}} = 10 \text{ } \mu\text{F}, \text{ } \text{T}_{\text{A}} = 25^{\circ}\text{C}, \text{ } \text{R}_{\text{L}} = 8 \text{ } \Omega \text{ (unless otherwise noted)}$ THD + NOISE THD + NOISE vs FREQUENCY (6 dB GAIN) vs FREQUENCY (6 dB GAIN) 10 10 % $V_{DD} = 3.6 V$ R_L = 4 Ω + 33 µH THD+N – Total Harmonic Distortion + Noise – % $P_0 = 50 \text{ mW}$ V_{DD} = 2.5 V $P_0 = 30 \text{ mW}$ P_o = 250 mW $P_o = 150 \text{ mW}$ $P_o = 400 \text{ mW}$ $R_{L} = 4 \Omega + 33 \mu H$ THD+N – Total Harmonic Distortion + Noise + $P_0 = 1 W$ Gain = 6 dB Gain = 6 dB 1 1 T 0 1 0.1 0.01 0.01 0.001 0.001 20 100 1k 10k 20k 20 100 1k f - Frequency - Hz f - Frequency - Hz Figure 18. Figure 19. THD + NOISE THD + NOISE vs OUTPUT POWER (12 dB GAIN) vs OUTPUT POWER (12 dB GAIN) 100 100 % % $V_{DD} = 2.5 V$ $R_1 = 4 \Omega + 33 \mu H$ $V_{DD} = 2.5 V$

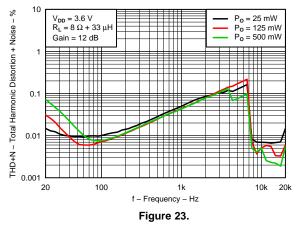




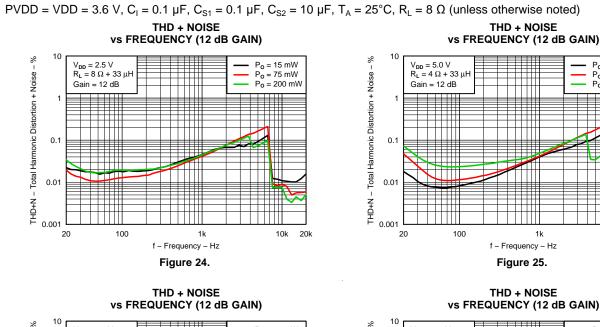




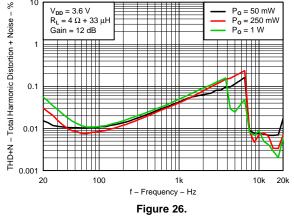
THD + NOISE vs FREQUENCY (12 dB GAIN)

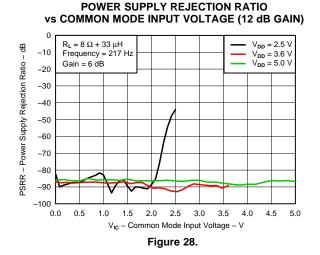


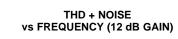
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TYPICAL CHARACTERISTICS (continued)







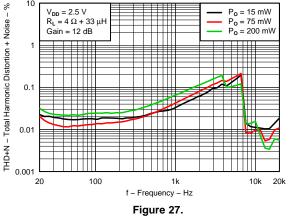
THD + NOISE

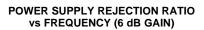
+

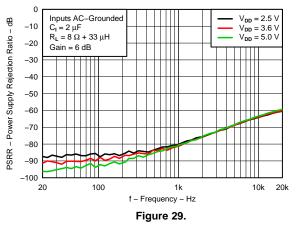
f - Frequency - Hz

Figure 25.

1k







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 $P_0 = 100 \text{ mW}$

 $P_0 = 500 \text{ mW}$

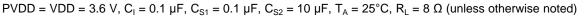
10k 20k

 $P_0 = 2 W$

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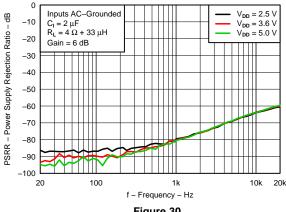


TYPICAL CHARACTERISTICS (continued)

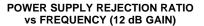


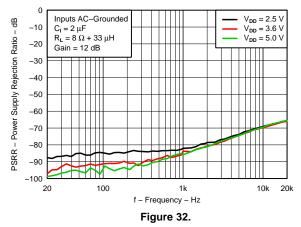


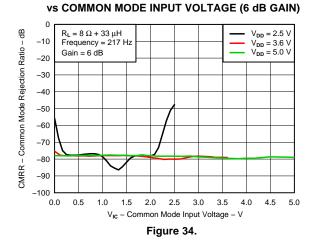
POWER SUPPLY REJECTION RATIO vs COMMON MODE INPUT VOLTAGE











COMMON MODE REJECTION RATIO

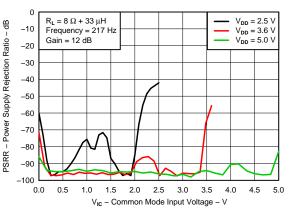
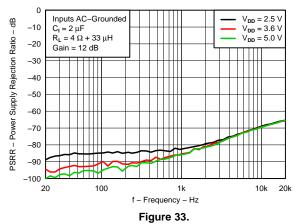
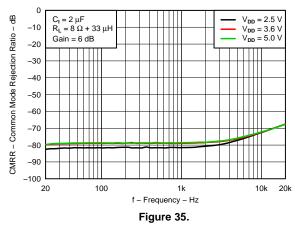


Figure 31.

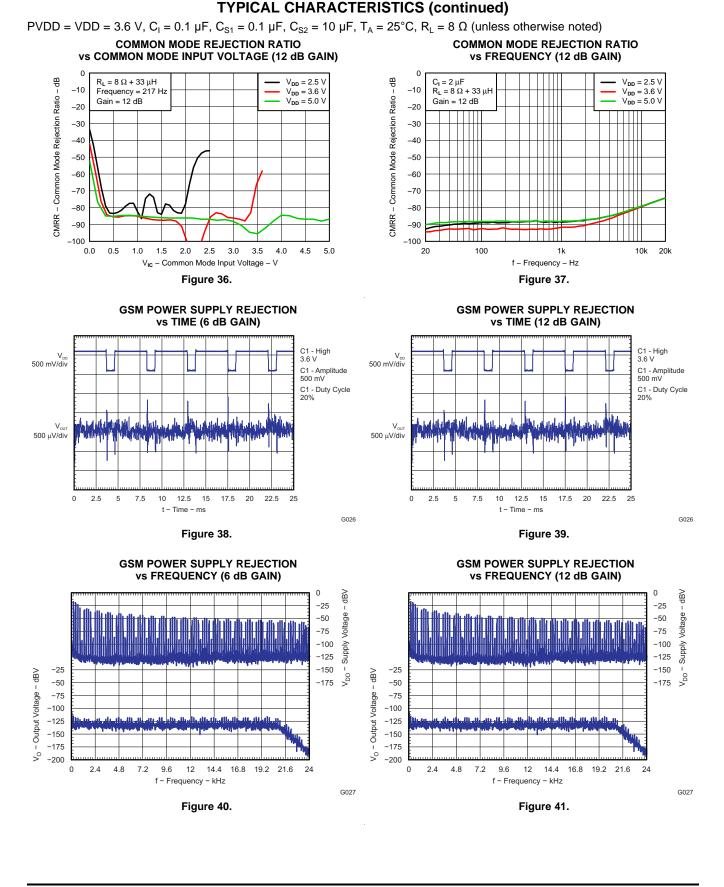
POWER SUPPLY REJECTION RATIO vs FREQUENCY (12 dB GAIN)



COMMON MODE REJECTION RATIO vs FREQUENCY (6 dB GAIN)



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APPLICATION INFORMATION

SHORT CIRCUIT AUTO-RECOVERY

When a short-circuit event occurs, the TPA2038D1 goes to shutdown mode and activates the integrated auto-recovery process whose aim is to return the device to normal operation once the short-circuit is removed. This process repeatedly examines (once every 100 ms) whether the short-circuit condition persists, and returns the device to normal operation immediately after the short-circuit condition is removed. This feature helps protect the device from large currents and maintain a good long-term reliability.

INTEGRATED IMAGE REJECT FILTER FOR DAC NOISE REJECTION

In applications which use a DAC to drive Class-D amplifiers, out-of-band noise energy present at the DAC's image frequencies fold back into the audio-band at the output of the Class-D amplifier. An external low-pass filter is often placed between the DAC and the Class-D amplifier in order to attenuate this noise.

The TPA2038D1 has an integrated Image Reject Filter with a low-pass cutoff frequency of 130 kHz, which significantly attenuates this noise. Depending on the system noise specification, the integrated Image Reject Filter may help eliminate external filtering, thereby saving board space and component cost.

COMPONENT SELECTION

Figure 42 shows the TPA2038D1 typical schematic with differential inputs, while Figure 43 shows the TPA2038D1 with differential inputs and input capacitors. Figure 44 shows the TPA2038D1 with a single-ended input.

Decoupling Capacitors (C_{S1}, C_{S2})

The TPA2038D1 is a high-performance class-D audio amplifier that requires adequate power supply decoupling to ensure the efficiency is high and total harmonic distortion (THD) is low. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor $C_{S1} = 0.1 \,\mu\text{F}$, placed as close as possible to the device V_{DD} lead works best. Placing C_{S1} close to the TPA2038D1 is important for the efficiency of the class-D amplifier, because any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency. For filtering lower-frequency noise signals, a 10 μ F or greater capacitor (C_{S2}) placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device. Typically, the smaller the capacitor's case size, the lower the inductance and the closer it can be placed to the TPA2038D1. X5R and X7R dielectric capacitors are recommended for both C_{S1} and C_{S2} .

Input Capacitors (C_I)

The TPA2038D1 does not require input coupling capacitors if the design uses a differential source that is biased within the common-mode input voltage range. That voltage range is listed in the Recommended Operating Conditions table. If the input signal is not biased within the recommended common-mode input range, such as in needing to use the input as a high pass filter, shown in Figure 43, or if using a single-ended source, shown in Figure 44, input coupling capacitors are required. The same value capacitors should be used on both IN+ and IN– for best pop performance. The 3 dB high-pass cutoff frequency f_c of the filter formed by the input coupling capacitor C_1 and the input resistance R_1 (typically 150 k Ω) of the TPA2038D1 is given by Equation 1:

$$f_{\rm C} = \frac{1}{\left(2\pi R_{\rm I} C_{\rm I}\right)} \tag{1}$$

The value of the input capacitor is important to consider as it directly affects the bass (low frequency) performance of the circuit. Speaker response may also be taken into consideration when setting the corner frequency using input capacitors. Solving for the input coupling capacitance, we get:

$$C_{I} = \frac{1}{\left(2\pi R_{I} f_{C}\right)}$$
⁽²⁾

If the corner frequency is within the audio band, the capacitors should have a tolerance of ±10% or better, because any mismatch in capacitance causes an impedance mismatch at the corner frequency and below.

For a flat low-frequency response, use large input coupling capacitors (0.1 µF or larger). X5R and X7R dielectric capacitors are recommended.

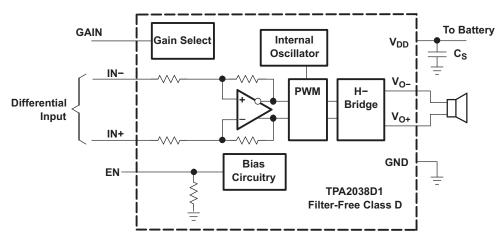


Figure 42. Typical TPA2038D1 Application Schematic With DC-coupled Differential Input

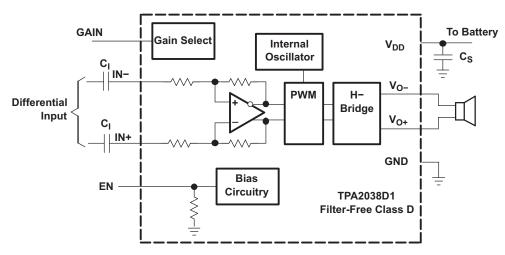


Figure 43. TPA2038D1 Application Schematic With Differential Input and Input Capacitors

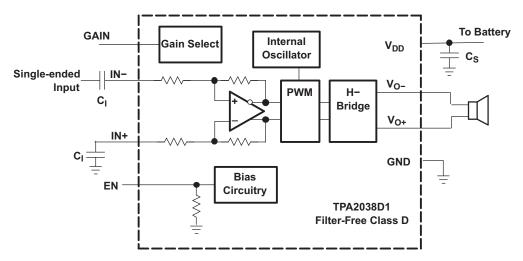


Figure 44. TPA2038D1 Application Schematic With Single-Ended Input



EFFICIENCY AND THERMAL INFORMATION

The maximum ambient operating temperature of the TPA2038D1 depends on the load resistance, power supply voltage and heat-sinking ability of the PCB system. The derating factor for the YFF package is shown in the dissipation rating table. Converting this to θ_{JA} :

$$\theta_{\rm JA} = \frac{1}{\rm Derating \ Factor}$$
(3)

Given θ_{JA} (from the Package Dissipation ratings table), the maximum allowable junction temperature (from the Absolute Maximum ratings table), and the maximum internal dissipation (from Power Dissipation vs Output Power figures) the maximum ambient temperature can be calculated with the following equation. Note that the units on these figures are Watts RMS. Because audio contains crest factors (ratio of peak power to RMS power) from 9–15 dB, thermal limitations are not usually encountered.

$$T_A Max = T_J Max - \theta_{JA} P_{Dmax}$$
(4)

The TPA2038D1 is designed with thermal protection that turns the device off when the junction temperature surpasses 150°C to prevent damage to the IC. Note that the use of speakers less resistive than 4 Ω (typ) is not advisable. Below 4 Ω (typ) the thermal performance of the device dramatically reduces because of increased output current and reduced amplifier efficiency. The Absolute Maximum rating of 3.2 Ω covers the manufacturing tolerance of a 4 Ω speaker and speaker impedance decrease due to frequency. θ_{JA} is a gross approximation of the complex thermal transfer mechanisms between the device and its ambient environment. If the θ_{JA} calculation reveals a potential problem, a more accurate estimate should be made.

WHEN TO USE AN OUTPUT FILTER

Design the TPA2038D1 without an Inductor / Capacitor (LC) output filter if the traces from the amplifier to the speaker are short. Wireless handsets and PDAs are great applications for this class-D amplifier to be used without an output filter.

The TPA2038D1 does not require an LC output filter for short speaker connections (approximately 100 mm long or less). A ferrite bead can often be used in the design if failing radiated emissions testing without an LC filter; and, the frequency-sensitive circuit is greater than 1 MHz. If choosing a ferrite bead, choose one with high impedance at high frequencies, but very low impedance at low frequencies. The selection must also take into account the currents flowing through the ferrite bead. Ferrites can begin to loose effectiveness at much lower than rated current values. See the EVM User's Guide (SLOU298) for components used successfully by TI.

Figure 45 shows a typical ferrite-bead output filter.

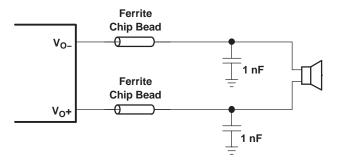


Figure 45. Typical Ferrite Chip Bead Filter

PRINTED CIRCUIT BOARD LAYOUT

In making the pad size for the WCSP balls, it is recommended that the layout use non-solder-mask-defined (NSMD) land. With this method, the solder mask opening is made larger than the desired land area, and the opening size is defined by the copper pad width. Figure 46 shows the appropriate diameters for a WCSP layout.

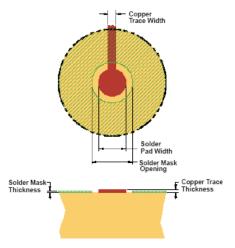


Figure 46. Land Pattern Image and Dimensions

SOLDER PAD DEFINITIONS			COPPER THICKNESS	STENCIL OPENING ⁽⁶⁾⁽⁷⁾	STENCIL THICKNESS
Non-solder-mask- defined (NSMD)	0.23 mm 0.310 mm		1 oz max (0.032 mm)	0.275 mm x 0.275 mm Sq. (rounded corners)	0.1 mm thick

- Circuit traces from NSMD defined PWB lands should be 75 μm to 100 μm wide in the exposed area inside the solder mask opening. Wider trace widths reduce device stand off and impact reliability.
- 2. Best reliability results are achieved when the PWB laminate glass transition temperature is above the operating the range of the intended application.
- 3. Recommend solder paste is Type 3 or Type 4.
- 4. For a PWB using a Ni/Au surface finish, the gold thickness should be less 0.5 mm to avoid a reduction in thermal fatigue performance.
- 5. Solder mask thickness should be less than 20 µm on top of the copper circuit pattern
- 6. Best solder stencil performance is achieved using laser cut stencils with electro polishing. Use of chemically etched stencils give inferior solder paste volume control.
- 7. Trace routing away from WCSP device should be balanced in X and Y directions to avoid unintentional component movement due to solder wetting forces.

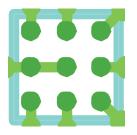


Figure 47. Layout Snapshot

An on-pad via is not required to route the middle ball B2 (PV_{DD}) of the TPA2038D1. Short ball B2 (PV_{DD}) to ball B1 (V_{DD}) and connect both to the supply trace as shown in Figure 47. This simplifies board routing and saves manufacturing cost.



PACKAGE DIMENSIONS

D	E			
Max = 1244µm	Max = 1190µm			
Min = 1184µm	Min = 1130µm			



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TPA2038D1YFFR	ACTIVE	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	
TPA2038D1YFFT	ACTIVE	DSBGA	YFF	9	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

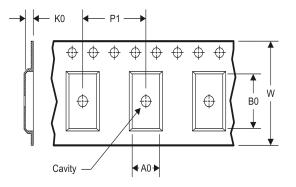
REEL DIMENSIONS

Texas Instruments





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

 TAPE AND REEL INFORMATION

 *All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA2038D1YFFT	DSBGA	YFF	9	250	180.0	8.4	1.34	1.34	0.81	4.0	8.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

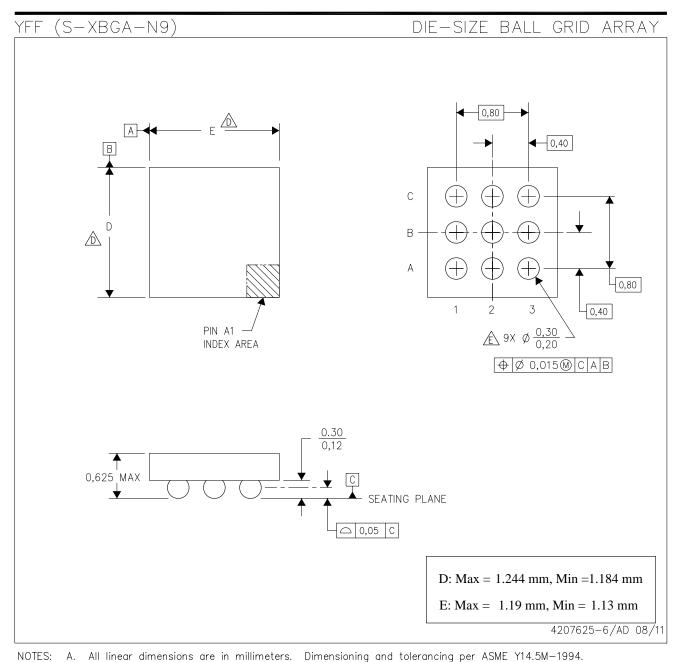
2-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TPA2038D1YFFT	DSBGA	YFF	9	250	210.0	185.0	35.0	

MECHANICAL DATA



NOTES:

B. This drawing is subject to change without notice.

- C. NanoFree™ package configuration.
- 🖄 The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative. E. Reference Product Data Sheet for array population.
- 3 x 3 matrix pattern is shown for illustration only.
- F. This package contains Pb-free balls.

NanoFree is a trademark of Texas Instruments



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